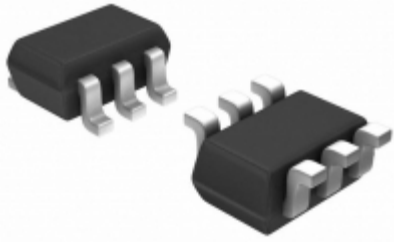
	<p>SI1905DL-T1-E3</p>
	<p>Hersteller-Teilenummer: SI1905DL-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2P-CH 8V 0.57A SC70-6</p> <p>Datenblätter:  SI1905DL-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 49947 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1905DL-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 8V 0.57A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	49947 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	270mW
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	570mA
Rds On (Max) @ Id, Vgs	600 mOhm @ 570mA, 4.5V
VGS (th) (Max) @ Id	450mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	2.3nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)













SI1905DL-T1-E3 ist neu im Original, Suche SI1905DL-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1905DL-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1905DL-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI1905DL VISHAY SI1905DL VISHAY	 SI1906DL-T1(PCH0) VISHAY SI1906DL-T1(PCH0) VISHAY	 SI1905BDH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 8V 0.63A SC70-6	 SI1906DL VISHAY VISHAY TO-263
 SI1905DL-T1 VISHAY SI1905DL-T1 VISHAY	 SI1905BDH-T1-E3 VISHAY SI1905BDH-T1-E3 VISHAY	 SI1906DL-T1 VISHAY SI1906DL-T1 VISHAY	 SI1905BDH-T1-GE3 V SI1905BDH-T1-GE3 V

heiße Teile

Mehr

- | | | | | |
|--|--|--|---|--|
|  SI1901DL-T1-E3 |  SI1902CDL-T1-GE3 |  SI1902CDL-T1-GE3 |  SI1902DL |  SI1902DL-T1 |
|  SI1902DL-T1-E1 |  SI1902DL-T1-E3 |  SI1902DL-T1-E3 |  SI1902DL-T1-GE3 |  SI1902DL-T1-GE3 |
|  SI1903DL |  SI1903DL-T1 |  SI1903DL-T1-E3 |  SI1903DL-T1-E3 |  SI1903DL-T1-GE3 |
|  SI1903DL-T1-GE3 |  SI1904EDH-T1 |  SI1904EDH-T1-GE3 |  SI1905BDH-T1-E3 |  SI1905BDH-T1-E3 |
|  SI1905BDH-T1-GE3 |  SI1905BDH-T1-E3 |  SI1905DL |  SI1905DL-T1 |  SI1905DL-T1-E3 |
|  SI1905DL-T1-GE3 |  SI1906DL-T1 |  SI1912EDH |  SI1912EDH-T1 |  SI1912EDH-T1-E3 |
|  SI1912EDH-T1-E3 |  SI1912EDH-T1-GE3 |  SI1913DH-T1-E3 |  SI1913DH-T1-E3 |  SI1913DH-T1-GE3 |
|  SI1913EDH-T1 |  SI1913EDH-T1-E3 |  SI1913EDH-T1-E3 |  SI1913EDH-T1-GE3 |  SI1917EDH-T1 |
|  SI1917EDH-T1-E3 |  SI1917EDH-T1-E3 |  SI1917EDH-T1-GE3 |  SI1922EDH-T1-GE3 |  SI1922EDH-T1-GE3 |
|  SI1926DL-T1-E3 |  SI1926DL-T1-E3 |  SI1926DL-T1-GE3 |  SI1926DL-T1-GE3 |  SI1958DH-T1-E3 |

Contact us: Info@Y-IC.com

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